

# BAL99

CASE 318-02/03, STYLE 17  
SOT-23 (TO-236AA/AB)

## SWITCHING DIODE

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	$V_R$	70	Vdc
Peak Forward Current	$I_F$	100	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
*Total Device Dissipation, $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	350 2.8	mW mW/ $^\circ\text{C}$
Storage Temperature	$T_{stg}$	150	$^\circ\text{C}$
*Thermal Resistance Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C/W}$

\*Package mounted on 99.5% alumina 10 x 8 x 0.6 mm.

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Voltage Leakage Current ( $V_R = 70\text{ V}$ ) ( $V_R = 25\text{ V}, T_J = 150^\circ\text{C}$ ) ( $V_R = 70\text{ V}, T_J = 150^\circ\text{C}$ )	$I_R$	— — —	2.5 30 50	$\mu\text{A}$
Reverse Breakdown Voltage ( $I_R = 100\ \mu\text{A}$ )	$V_{(BR)}$	70	—	V
Forward Voltage ( $I_F = 1.0\text{ mA}$ ) ( $I_F = 10\text{ mA}$ ) ( $I_F = 50\text{ mA}$ ) ( $I_F = 100\text{ mA}$ )	$V_F$	— — — —	715 855 1100 1300	mV
Recovery Current ( $I_F = 10\text{ mA}, V_R = 5.0\text{ V}, R_L = 500\ \Omega$ )	$Q_S$	—	45	pC
Diode Capacitance ( $V_R = 0, f = 1.0\text{ MHz}$ )	$C_D$	—	1.5	pF
Reverse Recovery Time ( $I_F = I_R = 10\text{ mA}, R_L = 100\ \Omega$ , measured at $I_R = 1.0\text{ mA}$ )	$t_{rr}$	—	6.0	ns
Forward Recovery Voltage ( $I_F = 10\text{ mA}, t_r = 20\text{ ns}$ )	$V_{FR}$	—	1.75	V